74HC4053-Q100; 74HCT4053-Q100

Triple 2-channel analog multiplexer/demultiplexer Rev. 2 — 22 November 2012 Prod

Product data sheet

General description

The 74HC4053-Q100; 74HCT4053-Q100 is a high-speed Si-gate CMOS device and is pin compatible with Low-power Schottky TTL (LSTTL). It is specified in compliance with JEDEC standard no. 7A.

The 74HC4053-Q100; 74HCT4053-Q100 is triple 2-channel analog multiplexer/demultiplexer with a common enable input (E). Each multiplexer/demultiplexer has two independent inputs/outputs (nY0 and nY1), a common input/output (nZ) and three digital select inputs (Sn). With \overline{E} LOW, one of the two switches is selected (low-impedance ON-state) by S1 to S3. With \overline{E} HIGH, all switches are in the high-impedance OFF-state, independent of S1 to S3.

 V_{CC} and GND are the supply voltage pins for the digital control inputs (S0 to S2, and \overline{E}). The V_{CC} to GND ranges are 2.0 V to 10.0 V for 74HC4053-Q100, and 4.5 V to 5.5 V for 74HCT4053-Q100. The analog inputs/outputs (nY0 to nY1, and nZ) can swing between V_{CC} as a positive limit and V_{EE} as a negative limit. V_{CC} – V_{EE} may not exceed 10.0 V.

For operation as a digital multiplexer/demultiplexer, V_{EE} is connected to GND (typically ground).

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

Features and benefits 2.

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - ◆ Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide analog input voltage range from -5 V to +5 V
- Low ON resistance:
 - 80 Ω (typical) at $V_{CC} V_{EE} = 4.5 \text{ V}$
 - 70 Ω (typical) at V_{CC} − V_{EE} = 6.0 V
 - 60 Ω (typical) at V_{CC} V_{EE} = 9.0 V
- Logic level translation: to enable 5 V logic to communicate with ±5 V analog signals
- Typical 'break before make' built-in
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
 - CDM AEC-Q100-011 revision B exceeds 1000 V
- Multiple package options



3. Applications

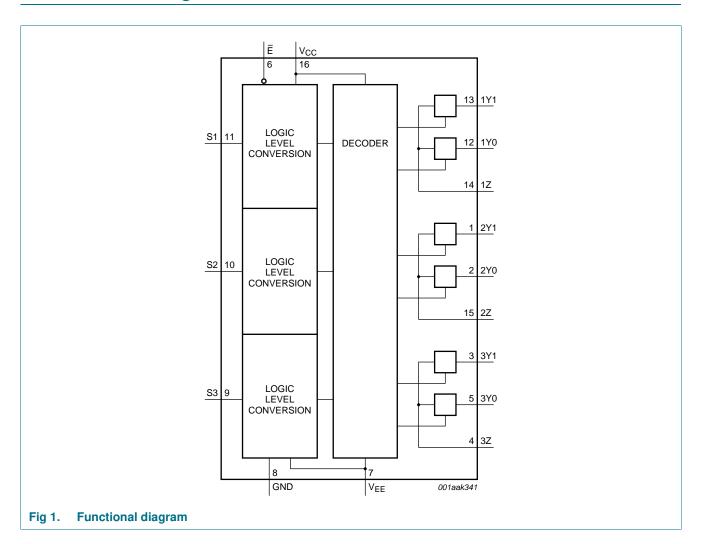
- Analog multiplexing and demultiplexing
- Digital multiplexing and demultiplexing
- Signal gating

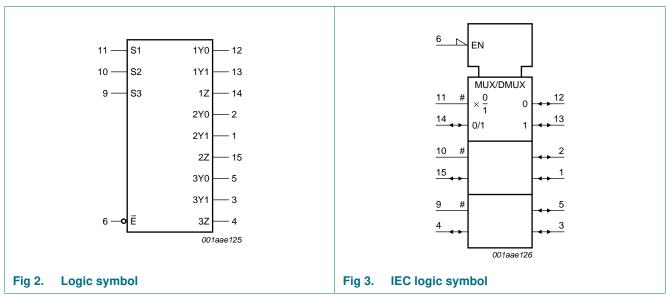
4. Ordering information

Table 1. Ordering information

Type number	Package							
	Temperature range	Name	Description	Version				
74HC4053D-Q100	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1				
74HCT4053D-Q100			body width 3.9 mm					
74HC4053PW-Q100	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1				
74HCT4053PW-Q100			body width 4.4 mm					
74HC4053BQ-Q100	–40 °C to +125 °C	DHVQFN16		SOT763-1				
74HCT4053BQ-Q100	_		very thin quad flat package; no leads; 16 terminals; body $2.5 \times 3.5 \times 0.85$ mm					

5. Functional diagram

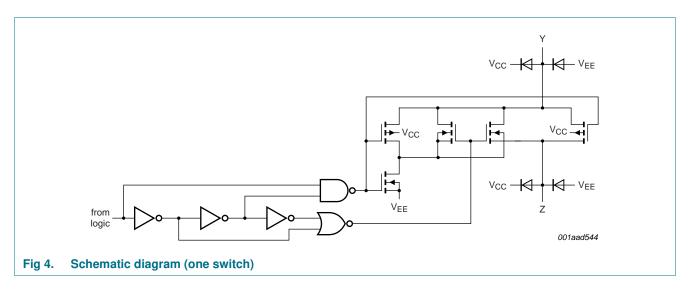




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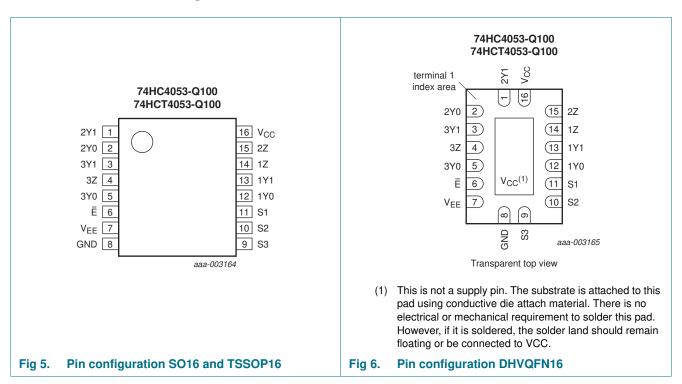
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6. Pinning information

6.1 Pinning



6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
Ē	6	enable input (active LOW)
V _{EE}	7	supply voltage
GND	8	ground supply voltage
S1, S2, S3	11, 10, 9	select input
1Y0, 2Y0, 3Y0	12, 2, 5	independent input or output
1Y1, 2Y1, 3Y1	13, 1, 3	independent input or output
1Z, 2Z, 3Z	14, 15, 4	common output or input
V _{CC}	16	supply voltage

7. Functional description

Table 3. Function table [1]

Inputs		Channel on
Ē	Sn	
L	L	nY0 to nZ
L	Н	nY1 to nZ
Н	X	switches off

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to $V_{SS} = 0 \text{ V}$ (ground).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		<u>[1]</u> –0.5	+11.0	V
I _{IK}	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I _{SK}	switch clamping current	$V_{SW} < -0.5 \ V$ or $V_{SW} > V_{CC} + 0.5 \ V$	-	±20	mA
I_{SW}	switch current	$-0.5 \text{ V} < \text{V}_{\text{SW}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	-	±25	mA
I _{EE}	supply current		-	±20	mA
I _{CC}	supply current		-	50	mA
I_{GND}	ground current		-	-50	mA
T_{stg}	storage temperature		- 65	+150	°C
P _{tot}	total power dissipation		[2] -	500	mW
Р	power dissipation	per switch	-	100	mW

^[1] To avoid drawing V_{CC} current out of terminal nZ, when switch current flows into terminals nYn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal nZ, no V_{CC} current flows out of terminals nYn. In this case, there is no limit for the voltage drop across the switch, but the voltages at nYn and nZ may not exceed V_{CC} or V_{EE} .

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^[2] For SO16 package: above 70 °C the value of P_{tot} derates linearly with 8 mW/K. For TSSOP16 package: above 60 °C the value of P_{tot} derates linearly with 5.5 mW/K. For DHVQFN16 package: above 60 °C the value of P_{tot} derates linearly with 4.5 mW/K.

9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	74H	IC4053-0	C4053-Q100		CT4053-	Q100	Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage	see <u>Figure 7</u> and <u>Figure 8</u>			•				
		V _{CC} – GND	2.0	5.0	10.0	4.5	5.0	5.5	V
		$V_{CC} - V_{EE}$	2.0	5.0	10.0	2.0	5.0	10.0	V
VI	input voltage		GND	-	V_{CC}	GND	-	V_{CC}	V
V_{SW}	switch voltage		V_{EE}	-	V_{CC}	V_{EE}	-	V_{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
$\Delta t/\Delta V$	input transition rise and fall	$V_{CC} = 2.0 \text{ V}$	-	-	625	-	-	-	ns/V
	rate	$V_{CC} = 4.5 \text{ V}$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 \text{ V}$	-	-	83	-	-	-	ns/V
		$V_{CC} = 10.0 \text{ V}$	-	-	31	-	-	-	ns/V

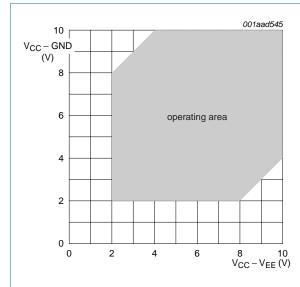


Fig 7. Guaranteed operating area as a function of the supply voltages for 74HC4053-Q100

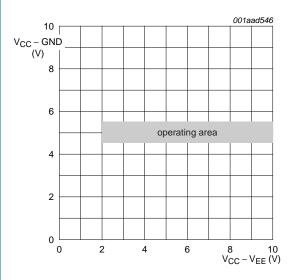


Fig 8. Guaranteed operating area as a function of the supply voltages for 74HCT4053-Q100

10. Static characteristics

R_{ON} resistance per switch for 74HC4053-Q100 and 74HCT4053-Q100 Table 6.

 $V_I = V_{IH}$ or V_{IL} ; for test circuit see <u>Figure 9</u>.

 V_{is} is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

For 74HC4053-Q100: V_{CC} – GND or V_{CC} – V_{EE} = 2.0 V, 4.5 V, 6.0 V and 9.0 V. For 74HCT4053-Q100: V_{CC} – GND = 4.5 V and 5.5 V, V_{CC} – V_{EE} = 2.0 V, 4.5 V, 6.0 V and 9.0 V.

Tamb = 25 °C	Unit
V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	
$\begin{array}{c} V_{CC} = 4.5 \; V; \; V_{EE} = 0 \; V; \; I_{SW} = 1000 \; \mu A & - & 100 & 180 \\ \hline V_{CC} = 6.0 \; V; \; V_{EE} = 0 \; V; \; I_{SW} = 1000 \; \mu A & - & 90 & 160 \\ \hline V_{CC} = 4.5 \; V; \; V_{EE} = -4.5 \; V; \; I_{SW} = 1000 \; \mu A & - & 70 & 130 \\ \hline \\ R_{ON(rail)} \\ \hline \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ $	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Ω
$ \begin{array}{ c c c c c } \hline V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V; } I_{SW} = 1000 \ \mu\text{A} & - & 70 & 130 \\ \hline \hline R_{ON(frail)} & ON \text{ resistance (rail)} & V_{is} = V_{EE} \\ \hline V_{CC} = 2.0 \ \text{V; } V_{EE} = 0 \ \text{V; } I_{SW} = 100 \ \mu\text{A} & 11 & - & 150 & - \\ \hline V_{CC} = 4.5 \ \text{V; } V_{EE} = 0 \ \text{V; } I_{SW} = 1000 \ \mu\text{A} & - & 80 & 140 \\ \hline V_{CC} = 6.0 \ \text{V; } V_{EE} = 0 \ \text{V; } I_{SW} = 1000 \ \mu\text{A} & - & 70 & 120 \\ \hline V_{CC} = 4.5 \ \text{V; } V_{EE} = 0 \ \text{V; } I_{SW} = 1000 \ \mu\text{A} & - & 60 & 105 \\ \hline V_{is} = V_{CC} \\ \hline V_{CC} = 2.0 \ \text{V; } V_{EE} = 0 \ \text{V; } I_{SW} = 1000 \ \mu\text{A} & - & 90 & 160 \\ \hline V_{is} = V_{CC} \\ \hline V_{CC} = 4.5 \ \text{V; } V_{EE} = 0 \ \text{V; } I_{SW} = 1000 \ \mu\text{A} & - & 90 & 160 \\ \hline V_{CC} = 4.5 \ \text{V; } V_{EE} = 0 \ \text{V; } I_{SW} = 1000 \ \mu\text{A} & - & 80 & 140 \\ \hline V_{CC} = 4.5 \ \text{V; } V_{EE} = 0 \ \text{V; } I_{SW} = 1000 \ \mu\text{A} & - & 65 & 120 \\ \hline \Delta R_{ON} \\ \hline \Delta R_{ON} \\ \hline \Delta R_{ON} \\ \hline ON \text{ resistance mismatch between channels} \\ \hline V_{is} = V_{CC} \text{ to } V_{EE} = 0 \ \text{V; }$	Ω
Ron(rail) ON resistance (rail) V _{is} = V _{EE} V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA 11 - 150 - V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA - 80 140 V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA - 70 120 V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA - 60 105 V _{is} = V _{CC} V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA - 60 105 V _{is} = V _{CC} V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA - 90 160 V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA - 80 140 V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA - 65 120 V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA - 65 120 V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA - 65 120 V _{CC} = 4.5 V; V _{EE} = 0 V V _{EE} V _{EE}	Ω
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$V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V; } I_{SW} = 1000 \mu\text{A} \qquad - \qquad 60 \qquad 105$ $V_{is} = V_{CC}$ $V_{CC} = 2.0 \text{ V; } V_{EE} = 0 \text{ V; } I_{SW} = 1000 \mu\text{A} \qquad [1] - \qquad 150 - \qquad V_{CC} = 4.5 \text{ V; } V_{EE} = 0 \text{ V; } I_{SW} = 1000 \mu\text{A} \qquad - \qquad 90 \qquad 160$ $V_{CC} = 4.5 \text{ V; } V_{EE} = 0 \text{ V; } I_{SW} = 1000 \mu\text{A} \qquad - \qquad 80 \qquad 140$ $V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V; } I_{SW} = 1000 \mu\text{A} \qquad - \qquad 65 \qquad 120$ $\Delta R_{ON} \qquad ON \text{ resistance mismatch between channels} \qquad V_{is} = V_{CC} \text{ to } V_{EE}$ $V_{CC} = 2.0 \text{ V; } V_{EE} = 0 \text{ V} \qquad \qquad [1] - \qquad - \qquad - \qquad V_{CC} = 4.5 \text{ V; } V_{EE} = 0 \text{ V} \qquad \qquad - \qquad 9 \qquad - \qquad V_{CC} = 4.5 \text{ V; } V_{EE} = 0 \text{ V} \qquad - \qquad 9 \qquad - \qquad V_{CC} = 4.5 \text{ V; } V_{EE} = 0 \text{ V} \qquad - \qquad 8 \qquad - \qquad V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V} \qquad - \qquad 6 \qquad - \qquad V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V} \qquad - \qquad 6 \qquad - \qquad V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V} \qquad - \qquad 6 \qquad - \qquad V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V} \qquad - \qquad 6 \qquad - \qquad V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V} \qquad - \qquad 6 \qquad - \qquad V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V} \qquad - \qquad 6 \qquad - \qquad V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V} \qquad - \qquad 6 \qquad - \qquad V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V} \qquad - \qquad 6 \qquad - \qquad V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V} \qquad - \qquad 6 \qquad - \qquad V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V} \qquad - \qquad 6 \qquad - \qquad V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V} \qquad - \qquad 6 \qquad - \qquad V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V} \qquad - \qquad 6 \qquad - \qquad V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V} \qquad - \qquad 6 \qquad - \qquad V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V} \qquad - \qquad 6 \qquad - \qquad V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V} \qquad - \qquad 6 \qquad - \qquad V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V} \qquad - \qquad 6 \qquad - \qquad V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V} \qquad - \qquad 6 \qquad - \qquad V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V} \qquad - \qquad 6 \qquad - \qquad V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V} \qquad - \qquad 6 \qquad - \qquad 0 \qquad - \qquad 0$	Ω
$V_{is} = V_{CC} \\ V_{CC} = 2.0 \text{ V; } V_{EE} = 0 \text{ V; } I_{SW} = 100 \mu\text{A} \\ V_{CC} = 2.0 \text{ V; } V_{EE} = 0 \text{ V; } I_{SW} = 1000 \mu\text{A} \\ V_{CC} = 4.5 \text{ V; } V_{EE} = 0 \text{ V; } I_{SW} = 1000 \mu\text{A} \\ V_{CC} = 6.0 \text{ V; } V_{EE} = 0 \text{ V; } I_{SW} = 1000 \mu\text{A} \\ V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V; } I_{SW} = 1000 \mu\text{A} \\ V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V; } I_{SW} = 1000 \mu\text{A} \\ V_{CC} = 2.0 \text{ V; } V_{EE} = 0 \text{ V} \\ V_{CC} = 2.0 \text{ V; } V_{EE} = 0 \text{ V} \\ V_{CC} = 4.5 \text{ V; } V_{EE} = 0 \text{ V} \\ V_{CC} = 4.5 \text{ V; } V_{EE} = 0 \text{ V} \\ V_{CC} = 4.5 \text{ V; } V_{EE} = 0 \text{ V} \\ V_{CC} = 4.5 \text{ V; } V_{EE} = 0 \text{ V} \\ V_{CC} = 4.5 \text{ V; } V_{EE} = 0 \text{ V} \\ V_{CC} = 4.5 \text{ V; } V_{EE} = 0 \text{ V} \\ V_{CC} = 4.5 \text{ V; } V_{EE} = 0 \text{ V} \\ V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V} \\ V_{CC} = 4.5 \text{ V; } V_{CC} = 4.5 \text$	Ω
$V_{CC} = 2.0 \text{ V; } V_{EE} = 0 \text{ V; } I_{SW} = 100 \mu\text{A} \qquad \boxed{11} - 150 - \\ V_{CC} = 4.5 \text{ V; } V_{EE} = 0 \text{ V; } I_{SW} = 1000 \mu\text{A} \qquad - 90 160 \\ V_{CC} = 6.0 \text{ V; } V_{EE} = 0 \text{ V; } I_{SW} = 1000 \mu\text{A} \qquad - 80 140 \\ V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V; } I_{SW} = 1000 \mu\text{A} \qquad - 65 120 \\ \hline \Delta R_{ON} \qquad \text{ON resistance mismatch between channels} \qquad \qquad V_{is} = V_{CC} \text{ to } V_{EE} \\ \hline V_{CC} = 2.0 \text{ V; } V_{EE} = 0 \text{ V} \qquad \qquad \boxed{11} - \qquad - - \\ V_{CC} = 4.5 \text{ V; } V_{EE} = 0 \text{ V} \qquad \qquad - 9 - \\ V_{CC} = 4.5 \text{ V; } V_{EE} = 0 \text{ V} \qquad \qquad - 8 - \\ V_{CC} = 6.0 \text{ V; } V_{EE} = 0 \text{ V} \qquad \qquad - 8 - \\ V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V} \qquad \qquad - 6 - \\ \hline T_{amb} = -40 \text{ °C to } +85 \text{ °C} \\ \hline R_{ON(peak)} \qquad \text{ON resistance (peak)} \qquad V_{is} = V_{CC} \text{ to } V_{EE} \qquad \qquad \qquad \\ \hline V_{is} = V_{CC} \text{ to } V_{EE} \qquad \qquad \qquad \qquad \qquad - \qquad \qquad$	Ω
$V_{CC} = 4.5 \text{ V; } V_{EE} = 0 \text{ V; } I_{SW} = 1000 \mu\text{A} \qquad - \qquad 90 \qquad 160$ $V_{CC} = 6.0 \text{ V; } V_{EE} = 0 \text{ V; } I_{SW} = 1000 \mu\text{A} \qquad - \qquad 80 \qquad 140$ $V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V; } I_{SW} = 1000 \mu\text{A} \qquad - \qquad 65 \qquad 120$ $\Delta R_{ON} \qquad \text{ON resistance mismatch between channels} \qquad V_{is} = V_{CC} \text{ to } V_{EE}$ $V_{CC} = 2.0 \text{ V; } V_{EE} = 0 \text{ V} \qquad \qquad \boxed{11} \text{ - } $	
$V_{CC} = 6.0 \text{ V; } V_{EE} = 0 \text{ V; } I_{SW} = 1000 \mu\text{A} \qquad - \qquad 80 \qquad 140$ $V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V; } I_{SW} = 1000 \mu\text{A} \qquad - \qquad 65 \qquad 120$ $\Delta R_{ON} \qquad \text{ON resistance mismatch between channels} \qquad V_{is} = V_{CC} \text{ to } V_{EE}$ $V_{CC} = 2.0 \text{ V; } V_{EE} = 0 \text{ V} \qquad \qquad - $	Ω
$V_{CC} = 4.5 \text{ V; } V_{EE} = -4.5 \text{ V; } I_{SW} = 1000 \mu\text{A} \qquad - \qquad 65 \qquad 120$ $\Delta R_{ON} \qquad \text{ON resistance mismatch between channels} \qquad V_{is} = V_{CC} \text{ to } V_{EE}$ $V_{CC} = 2.0 \text{ V; } V_{EE} = 0 \text{ V} \qquad \qquad \boxed{11} - \qquad -$	Ω
	Ω
between channels	Ω
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	
	Ω
$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$ $- 6 - 6$ $T_{amb} = -40 \text{ °C to +85 °C}$ $R_{ON(peak)} \text{ ON resistance (peak)} \qquad V_{is} = V_{CC} \text{ to } V_{EE}$	Ω
T _{amb} = -40 °C to +85 °C R _{ON(peak)} ON resistance (peak) V _{is} = V _{CC} to V _{EE}	Ω
$R_{ON(peak)}$ ON resistance (peak) $V_{is} = V_{CC}$ to V_{EE}	Ω
$V_{CC} = 2.0 \text{ V}$: $V_{EE} = 0 \text{ V}$: $I_{CW} = 100 \text{ µA}$ [1]	
	Ω
$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 1000 \mu A$ 225	Ω
$V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V}; I_{SW} = 1000 \mu A$ 200	Ω
$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}; I_{SW} = 1000 \mu A$ - 165	Ω

R_{ON} resistance per switch for 74HC4053-Q100 and 74HCT4053-Q100 ...continued

 $V_I = V_{IH}$ or V_{IL} ; for test circuit see <u>Figure 9</u>.

 V_{is} is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

For 74HC4053-Q100: V_{CC} – GND or V_{CC} – V_{EE} = 2.0 V, 4.5 V, 6.0 V and 9.0 V. For 74HCT4053-Q100: V_{CC} – GND = 4.5 V and 5.5 V, V_{CC} – V_{EE} = 2.0 V, 4.5 V, 6.0 V and 9.0 V.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{ON(rail)}$	ON resistance (rail)	$V_{is} = V_{EE}$				
		V_{CC} = 2.0 V; V_{EE} = 0 V; I_{SW} = 100 μA	<u>[1]</u> -	-	-	Ω
		V_{CC} = 4.5 V; V_{EE} = 0 V; I_{SW} = 1000 μA	-	-	175	Ω
		V_{CC} = 6.0 V; V_{EE} = 0 V; I_{SW} = 1000 μA	-	-	150	Ω
		V_{CC} = 4.5 V; V_{EE} = -4.5 V; I_{SW} = 1000 μA	-	-	130	Ω
		$V_{is} = V_{CC}$				
		V_{CC} = 2.0 V; V_{EE} = 0 V; I_{SW} = 100 μA	<u>[1]</u> _	-	-	Ω
		V_{CC} = 4.5 V; V_{EE} = 0 V; I_{SW} = 1000 μA	-	-	200	Ω
		V_{CC} = 6.0 V; V_{EE} = 0 V; I_{SW} = 1000 μA	-	-	175	Ω
		V_{CC} = 4.5 V; V_{EE} = -4.5 V; I_{SW} = 1000 μA	-	-	150	Ω
$T_{amb} = -4$	10 °C to +125 °C					
R _{ON(peak)}	ON resistance (peak)	$V_{is} = V_{CC}$ to V_{EE}				
		V_{CC} = 2.0 V; V_{EE} = 0 V; I_{SW} = 100 μA	<u>[1]</u> _	-	-	Ω
		V_{CC} = 4.5 V; V_{EE} = 0 V; I_{SW} = 1000 μA	-	-	270	Ω
		V_{CC} = 6.0 V; V_{EE} = 0 V; I_{SW} = 1000 μA	-	-	240	Ω
		V_{CC} = 4.5 V; V_{EE} = -4.5 V; I_{SW} = 1000 μA	-	-	195	Ω
R _{ON(rail)}	ON resistance (rail)	$V_{is} = V_{EE}$				
		V_{CC} = 2.0 V; V_{EE} = 0 V; I_{SW} = 100 μA	<u>[1]</u> _	-	-	Ω
		V_{CC} = 4.5 V; V_{EE} = 0 V; I_{SW} = 1000 μA	-	-	210	Ω
		V_{CC} = 6.0 V; V_{EE} = 0 V; I_{SW} = 1000 μA	-	-	180	Ω
		V_{CC} = 4.5 V; V_{EE} = -4.5 V; I_{SW} = 1000 μA	-	-	160	Ω
		$V_{is} = V_{CC}$				
		V_{CC} = 2.0 V; V_{EE} = 0 V; I_{SW} = 100 μA	[1] -	-	-	Ω
		V_{CC} = 4.5 V; V_{EE} = 0 V; I_{SW} = 1000 μA	-	-	240	Ω
		V_{CC} = 6.0 V; V_{EE} = 0 V; I_{SW} = 1000 μA	-	-	210	Ω
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}; I_{SW} = 1000 \mu\text{A}$	-	-	180	Ω

^[1] When supply voltages (V_{CC} - V_{EE}) near 2.0 V the analog switch ON resistance becomes extremely non-linear. When using a supply of 2 V, only use these devices for transmitting digital signals.

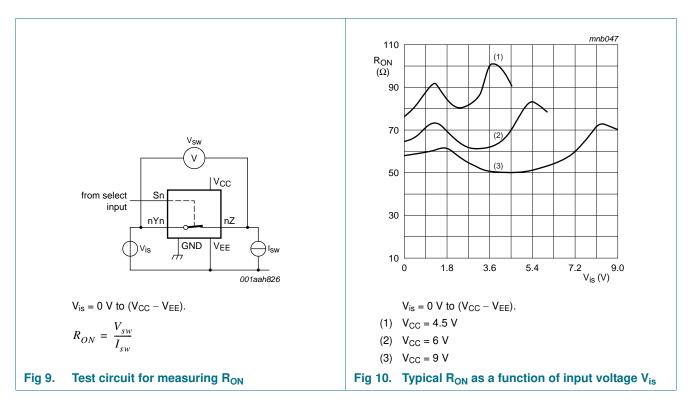


Table 7. Static characteristics for 74HC4053-Q100

Voltages are referenced to GND (ground = 0 V).

 V_{is} is the input voltage at pins nYn or nZ, whichever is assigned as an input.

 V_{os} is the output voltage at pins nZ or nYn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 25	°C					
V_{IH}	HIGH-level input	V _{CC} = 2.0 V	1.5	1.2	-	V
	voltage	V _{CC} = 4.5 V	3.15	2.4	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	V
		V _{CC} = 9.0 V	6.3	4.7	-	V
V _{IL}	LOW-level input	V _{CC} = 2.0 V	-	8.0	0.5	V
	voltage	V _{CC} = 4.5 V	-	2.1	1.35	٧
		V _{CC} = 6.0 V	-	2.8	1.8	٧
		V _{CC} = 9.0 V	-	4.3	2.7	٧
l _l	input leakage current	$V_{EE} = 0 \text{ V}; V_I = V_{CC} \text{ or GND}$				
		V _{CC} = 6.0 V	-	-	±0.1	μΑ
		V _{CC} = 10.0 V	-	-	±0.2	μА
I _{S(OFF)}	OFF-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; see Figure 11				
		per channel	-	-	±0.1	μΑ
		all channels	-	-	±0.1	μΑ
I _{S(ON)}	ON-state leakage current	$V_I = V_{IH}$ or V_{IL} ; $ V_{SW} = V_{CC} - V_{EE}$; $V_{CC} = 10.0$ V; $V_{EE} = 0$ V; see Figure 12	-	-	±0.1	μА

Table 7. Static characteristics for 74HC4053-Q100 ...continued

Voltages are referenced to GND (ground = 0 V).

 V_{is} is the input voltage at pins nYn or nZ, whichever is assigned as an input.

 V_{os} is the output voltage at pins nZ or nYn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CC}	supply current	V_{EE} = 0 V; V_{I} = V_{CC} or GND; V_{is} = V_{EE} or V_{CC} ; V_{os} = V_{CC} or V_{EE}				
		V _{CC} = 6.0 V	-	-	8.0	μА
		V _{CC} = 10.0 V	-	-	16.0	μА
Cı	input capacitance		-	3.5	-	pF
C _{sw}	switch capacitance	independent pins nYn	-	5	-	pF
		common pins nZ	-	8	-	pF
T _{amb} = -40	0 °C to +85 °C					
V _{IH}	HIGH-level input	$V_{CC} = 2.0 \text{ V}$	1.5	-	-	V
	voltage	V _{CC} = 4.5 V	3.15	-	-	V
		$V_{CC} = 6.0 \text{ V}$	4.2	-	-	V
		V _{CC} = 9.0 V	6.3	-	-	V
V _{IL}	LOW-level input	$V_{CC} = 2.0 \text{ V}$	-	-	0.5	V
	voltage	$V_{CC} = 4.5 \text{ V}$	-	-	1.35	V
		$V_{CC} = 6.0 \text{ V}$	-	-	1.8	V
		V _{CC} = 9.0 V	-	-	2.7	V
l _l	input leakage current	$V_{EE} = 0 \text{ V}; V_{I} = V_{CC} \text{ or GND}$				
		$V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μΑ
		V _{CC} = 10.0 V	-	-	±2.0	μΑ
I _{S(OFF)}	OFF-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; see Figure 11				
		per channel	-	-	±1.0	μΑ
		all channels	-	-	±1.0	μΑ
I _{S(ON)}	ON-state leakage current	$V_I = V_{IH}$ or V_{IL} ; $ V_{SW} = V_{CC} - V_{EE}$; $V_{CC} = 10.0$ V; $V_{EE} = 0$ V; see Figure 12	-	-	±1.0	μΑ
I _{CC}	supply current	V_{EE} = 0 V; V_{I} = V_{CC} or GND; V_{is} = V_{EE} or V_{CC} ; V_{os} = V_{CC} or V_{EE}				
		$V_{CC} = 6.0 \text{ V}$	-	-	80.0	μΑ
		$V_{CC} = 10.0 \text{ V}$	-	-	160.0	μΑ
T _{amb} = -40	0 °C to +125 °C					
V _{IH}	HIGH-level input	V _{CC} = 2.0 V	1.5	-	-	V
	voltage	V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
		V _{CC} = 9.0 V	6.3	-	-	V
V _{IL}	LOW-level input	$V_{CC} = 2.0 \text{ V}$	-	-	0.5	V
	voltage	$V_{CC} = 4.5 \text{ V}$	-	-	1.35	V
		$V_{CC} = 6.0 \text{ V}$	-	-	1.8	V
		V _{CC} = 9.0 V	-	-	2.7	V

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Table 7. Static characteristics for 74HC4053-Q100 ...continued

Voltages are referenced to GND (ground = 0 V).

 V_{is} is the input voltage at pins nYn or nZ, whichever is assigned as an input.

 V_{os} is the output voltage at pins nZ or nYn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
l _l	input leakage current	$V_{EE} = 0 \text{ V}; V_I = V_{CC} \text{ or GND}$				
		V _{CC} = 6.0 V	-	-	±1.0	μΑ
		V _{CC} = 10.0 V	-	-	±2.0	μΑ
I _{S(OFF)}	OFF-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; see <u>Figure 11</u>				
		per channel	-	-	±1.0	μΑ
		all channels	-	-	±1.0	μΑ
I _{S(ON)}	ON-state leakage current	$V_I = V_{IH}$ or V_{IL} ; $ V_{SW} = V_{CC} - V_{EE}$; $V_{CC} = 10.0$ V; $V_{EE} = 0$ V; see Figure 12	-	-	±1.0	μΑ
I _{CC}	supply current	V_{EE} = 0 V; V_{I} = V_{CC} or GND; V_{is} = V_{EE} or V_{CC} ; V_{os} = V_{CC} or V_{EE}				
		V _{CC} = 6.0 V	-	-	160.0	μΑ
		V _{CC} = 10.0 V	-	-	320.0	μΑ

Table 8. Static characteristics for 74HCT4053-Q100

Voltages are referenced to GND (ground = 0 V).

 V_{is} is the input voltage at pins nYn or nZ, whichever is assigned as an input.

 V_{os} is the output voltage at pins nZ or nYn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 25	°C					
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	V
V_{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	V
l _l	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$; $V_{EE} = 0 \text{ V}$	-	-	±0.1	μΑ
I _{S(OFF)}	OFF-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_I = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; see Figure 11				
		per channel	-	-	±0.1	μΑ
		all channels	-	-	±0.1	μΑ
I _{S(ON)}	ON-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; see Figure 12	-	-	±0.1	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = V_{EE}$ or V_{CC} ; $V_{os} = V_{CC}$ or V_{EE}				
		$V_{CC} = 5.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	8.0	μА
		$V_{CC} = 5.0 \text{ V}; V_{EE} = -5.0 \text{ V}$	-	-	16.0	μА
ΔI_{CC}	additional supply current	per input; $V_I = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V; $V_{EE} = 0 \text{ V}$	-	50	180	μА
C _I	input capacitance		-	3.5	-	рF
C _{sw}	switch capacitance	independent pins nYn	-	5	-	рF
		common pins nZ	-	8	-	рF

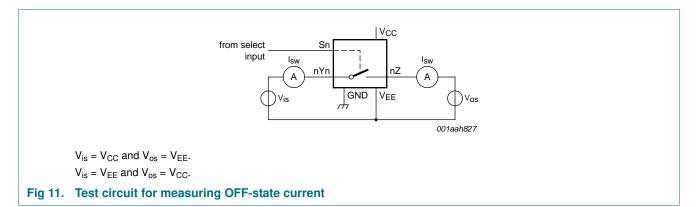
Table 8. Static characteristics for 74HCT4053-Q100 ...continued

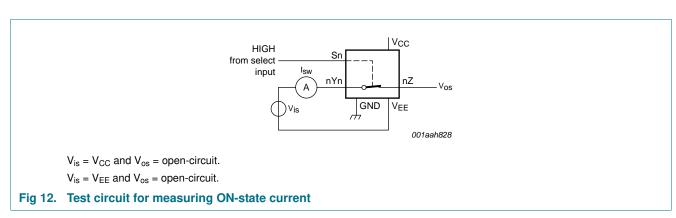
Voltages are referenced to GND (ground = 0 V).

 V_{is} is the input voltage at pins nYn or nZ, whichever is assigned as an input.

 V_{os} is the output voltage at pins nZ or nYn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -40	0 °C to +85 °C					
V _{IH}	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	-	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	-	0.8	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$; $V_{EE} = 0 \text{ V}$	-	-	±1.0	μΑ
I _{S(OFF)}	OFF-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; see Figure 11				
		per channel	-	-	±1.0	μА
		all channels	-	-	±1.0	μΑ
I _{S(ON)}	ON-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; see Figure 12	-	-	±1.0	μА
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = V_{EE}$ or V_{CC} ; $V_{os} = V_{CC}$ or V_{EE}				
		V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	80.0	μΑ
		$V_{CC} = 5.0 \text{ V}; V_{EE} = -5.0 \text{ V}$	-	-	160.0	μΑ
Δl _{CC}	additional supply current	per input; $V_I = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V; $V_{EE} = 0 \text{ V}$	-	-	225	μА
T _{amb} = -40	0 °C to +125 °C					
V_{IH}	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	-	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	-	0.8	V
l _l	input leakage current	V_{I} = V_{CC} or GND; V_{CC} = 5.5 V; V_{EE} = 0 V	-	-	±1.0	μΑ
I _{S(OFF)}	OFF-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; see Figure 11				
		per channel	-	-	±1.0	μΑ
		all channels	-	-	±1.0	μΑ
I _{S(ON)}	ON-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; see Figure 12	-	-	±1.0	μА
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = V_{EE}$ or V_{CC} ; $V_{os} = V_{CC}$ or V_{EE}				
		$V_{CC} = 5.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	160.0	μΑ
		$V_{CC} = 5.0 \text{ V}; V_{EE} = -5.0 \text{ V}$	-	-	320.0	μΑ
Δl _{CC}	additional supply current	per input; $V_I = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V; $V_{EE} = 0 \text{ V}$	-	-	245	μА





11. Dynamic characteristics

Table 9. Dynamic characteristics for 74HC4053-Q100

GND = 0 V; $t_f = t_f = 6 \text{ ns}$; $C_L = 50 \text{ pF}$; for test circuit see Figure 15.

 V_{is} is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 25	°C					
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see <u>Figure 13</u>	<u>[1]</u>			
		$V_{CC} = 2.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	15	60	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	5	12	ns
		$V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	4	10	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	4	8	ns
t _{on}	turn-on time	\overline{E} to $V_{os};R_{L}=\infty\Omega;see\underline{Figure14}$	[2]			
		$V_{CC} = 2.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	60	220	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	20	44	ns
		$V_{CC} = 5.0 \text{ V}; V_{EE} = 0 \text{ V}; C_L = 15 \text{ pF}$	-	17	-	ns
		$V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	16	37	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	15	31	ns
		Sn to V_{os} ; $R_L = \infty \Omega$; see Figure 14	<u>[2]</u>			
		$V_{CC} = 2.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	75	220	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	25	44	ns
		$V_{CC} = 5.0 \text{ V}; V_{EE} = 0 \text{ V}; C_L = 15 \text{ pF}$	-	21	-	ns
		$V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	20	37	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	15	31	ns
off	turn-off time	\overline{E} to V_{os} ; $R_L = 1 \text{ k}\Omega$; see $\underline{Figure 14}$	<u>[3]</u>			
		$V_{CC} = 2.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	63	210	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	21	42	ns
		$V_{CC} = 5.0 \text{ V}; V_{EE} = 0 \text{ V}; C_L = 15 \text{ pF}$	-	18	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	17	36	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	15	29	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14	[3]			
		$V_{CC} = 2.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	60	210	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	20	42	ns
		$V_{CC} = 5.0 \text{ V}; V_{EE} = 0 \text{ V}; C_L = 15 \text{ pF}$	-	17	-	ns
		$V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	16	36	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	15	29	ns
C_PD	power dissipation capacitance	per switch; $V_I = GND$ to V_{CC}	[4] -	36	-	pF

 Table 9.
 Dynamic characteristics for 74HC4053-Q100 ...continued

 $GND = 0 \ V; t_r = t_f = 6 \ ns; C_L = 50 \ pF;$ for test circuit see <u>Figure 15</u>.

 V_{is} is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$T_{amb} = -4$	0 °C to +85 °C					
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see <u>Figure 13</u>	[1]			
		$V_{CC} = 2.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	75	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	15	ns
		$V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	13	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	10	ns
t _{on}	turn-on time	\overline{E} to $V_{os};R_{L}=\infty\Omega;see\underline{Figure14}$	[2]			
		$V_{CC} = 2.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	275	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	55	ns
		$V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	47	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	39	ns
		Sn to V_{os} ; $R_L = \infty \Omega$; see Figure 14	[2]			
		$V_{CC} = 2.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	275	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	55	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	47	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	39	ns
t _{off}	turn-off time	\overline{E} to $V_{os};R_{L}=1\;k\Omega;see\;\underline{Figure\;14}$	[3]			
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	265	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	53	ns
		$V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	45	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	36	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14	[3]			
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	265	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	53	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	45	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	36	ns
T _{amb} = -4	0 °C to +125 °C					
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_{L} = \infty \Omega$; see <u>Figure 13</u>	[1]			
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	90	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	18	ns
		$V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	15	ns
		$V_{CC} = 4.5 \text{ V}; V_{FF} = -4.5 \text{ V}$	_	_	12	ns

 Table 9.
 Dynamic characteristics for 74HC4053-Q100 ...continued

 $GND = 0 \ V; t_r = t_f = 6 \ ns; C_L = 50 \ pF;$ for test circuit see <u>Figure 15</u>.

 V_{is} is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{on}	turn-on time	\overline{E} to $V_{os};R_{L}=\infty\Omega;see\underline{Figure14}$	<u>[2]</u>			
		$V_{CC} = 2.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	330	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	66	ns
		$V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	56	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	47	ns
		Sn to V_{os} ; $R_L = \infty \Omega$; see Figure 14	[2]			
		$V_{CC} = 2.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	330	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	66	ns
		$V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	56	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	47	ns
t _{off}	turn-off time	\overline{E} to V_{os} ; $R_L = 1 \text{ k}\Omega$; see $\underline{Figure 14}$	[3]			
		$V_{CC} = 2.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	315	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	63	ns
		$V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	54	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	44	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14	[3]			
		$V_{CC} = 2.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	315	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	63	ns
		$V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	54	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	44	ns

^[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

[4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}{}^2 \times f_i \times N + \Sigma \{(C_L + C_{sw}) \times V_{CC}{}^2 \times f_o\}$$
 where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

N = number of inputs switching;

 $\Sigma \{(C_L + C_{sw}) \times V_{CC}{}^2 \times f_o\} = sum \ of \ outputs;$

 C_L = output load capacitance in pF;

 C_{sw} = switch capacitance in pF;

 V_{CC} = supply voltage in V.

^[2] ton is the same as tPZH and tPZL.

^[3] t_{off} is the same as t_{PHZ} and t_{PLZ} .

Table 10. Dynamic characteristics for 74HCT4053-Q100

 $GND = 0 \ V; t_r = t_f = 6 \ ns; \ C_L = 50 \ pF; for test circuit see <u>Figure 15</u>.$

 V_{is} is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see Figure 13	<u>[1]</u>			
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	5	12	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	4	8	ns
t _{on}	turn-on time	\overline{E} to V_{os} ; $R_L = 1 \text{ k}\Omega$; see $\underline{Figure 14}$	[2]			
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	27	48	ns
		$V_{CC} = 5.0 \text{ V}; V_{EE} = 0 \text{ V}; C_L = 15 \text{ pF}$	-	23	-	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	16	34	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14	[2]			
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	25	48	ns
		$V_{CC} = 5.0 \text{ V}; V_{EE} = 0 \text{ V}; C_L = 15 \text{ pF}$	-	21	-	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	16	34	ns
t _{off}	turn-off time	\overline{E} to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14	[3]			
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	24	44	ns
		$V_{CC} = 5.0 \text{ V}; V_{EE} = 0 \text{ V}; C_L = 15 \text{ pF}$	-	20	-	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	15	31	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14	[3]			
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	22	44	ns
		$V_{CC} = 5.0 \text{ V}; V_{EE} = 0 \text{ V}; C_L = 15 \text{ pF}$	-	19	-	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	15	31	ns
C _{PD}	power dissipation capacitance	per switch; $V_I = GND$ to $V_{CC} - 1.5 V$	[4] -	36	-	pF
T _{amb} = -	40 °C to +85 °C					
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see Figure 13	[1]			
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	15	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	10	ns
t _{on}	turn-on time	\overline{E} to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14	[2]			
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	60	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	43	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14	[2]			
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	60	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	43	ns
t _{off}	turn-off time	\overline{E} to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14	[3]			
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	55	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	39	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14	[3]			
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	55	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	39	ns
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Table 10. Dynamic characteristics for 74HCT4053-Q100 ...continued

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF; for test circuit see <u>Figure 15</u>.

 V_{is} is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$T_{amb} = -4$	0 °C to +125 °C					
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see Figure 13	[1]			
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	18	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	12	ns
t _{on}	turn-on time	\overline{E} to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14	[2]			
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	72	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	51	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14	[2]			
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	72	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	51	ns
t _{off}	turn-off time	\overline{E} to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14	[3]			
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	66	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	47	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14	[3]			
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	66	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	-	47	ns

- [1] t_{pd} is the same as t_{PHL} and t_{PLH} .
- [2] t_{on} is the same as t_{PZH} and t_{PZL} .
- [3] t_{off} is the same as t_{PHZ} and t_{PLZ} .
- [4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma \{ (C_L + C_{sw}) \times V_{CC}^2 \times f_o \} \text{ where: }$$

f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

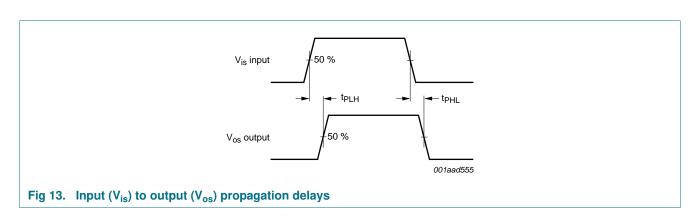
N = number of inputs switching;

 $\Sigma \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\} = sum of outputs;$

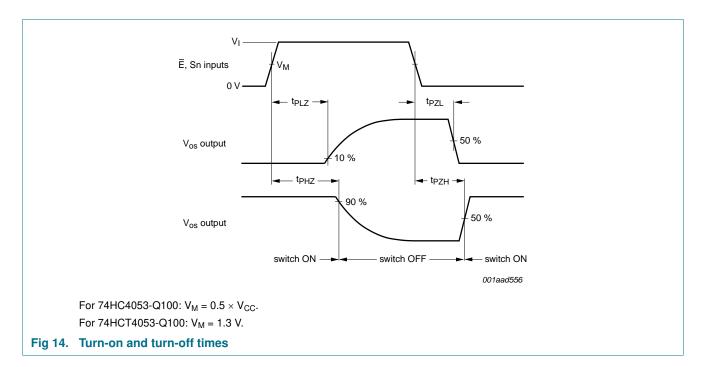
C_L = output load capacitance in pF;

C_{sw} = switch capacitance in pF;

V_{CC} = supply voltage in V.



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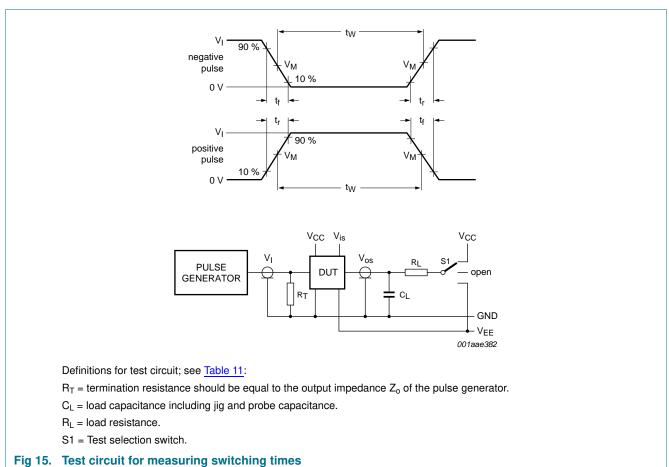


Table 11. Test data

Test	Input				Load		S1 position
	VI	V _{is}	t _r , t _f	t _r , t _f at f _{max} other[1]		R _L	
			at f _{max}				
t _{PHL} , t _{PLH}	[2]	pulse	< 2 ns	6 ns	50 pF	1 kΩ	open
t _{PZH} , t _{PHZ}	[2]	V _{CC}	< 2 ns	6 ns	50 pF	1 kΩ	V_{EE}
t _{PZL} , t _{PLZ}	[2]	V_{EE}	< 2 ns	6 ns	50 pF	1 kΩ	V_{CC}

- [1] $t_r = t_f = 6$ ns; when measuring f_{max} , there is no constraint to t_r and t_f with 50 % duty factor.
- [2] V_I values:
 - a) For 74HC4053-Q100: $V_I = V_{CC}$
 - b) For 74HCT4053-Q100: $V_1 = 3 \text{ V}$

11.1 Additional dynamic characteristics

Table 12. Additional dynamic characteristics

Recommended conditions and typical values; $GND = 0 \ V$; $T_{amb} = 25 \ ^{\circ}C$; $C_L = 50 \ pF$. V_{is} is the input voltage at pins nYn or nZ, whichever is assigned as an input. V_{os} is the output voltage at pins nYn or nZ, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
d _{sin}	sine-wave distortion	$f_i = 1 \text{ kHz}$; $R_L = 10 \text{ k}\Omega$; see Figure 16				
		$V_{is} = 4.0 \text{ V (p-p)}; V_{CC} = 2.25 \text{ V}; V_{EE} = -2.25 \text{ V}$	-	0.04	-	%
		$V_{is} = 8.0 \text{ V (p-p)}; V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	0.02	-	%
		$f_i = 10 \text{ kHz}$; $R_L = 10 \text{ k}\Omega$; see Figure 16				
		$V_{is} = 4.0 \text{ V (p-p)}; V_{CC} = 2.25 \text{ V}; V_{EE} = -2.25 \text{ V}$	-	0.12	-	%
		$V_{is} = 8.0 \text{ V (p-p)}; V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	0.06	-	%
α_{iso}	isolation (OFF-state)	$R_L = 600 \Omega$; $f_i = 1 MHz$; see Figure 17				
		$V_{CC} = 2.25 \text{ V}; V_{EE} = -2.25 \text{ V}$	<u>[1]</u> _	-50	-	dB
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	[1] _	-50	-	dB
Xtalk	crosstalk	between two switches/multiplexers; $R_L = 600 \Omega$; $f_i = 1 MHz$; see Figure 18				
		$V_{CC} = 2.25 \text{ V}; V_{EE} = -2.25 \text{ V}$	[1] -	-60	-	dB
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	[1] -	-60	-	dB
V _{ct}	crosstalk voltage	peak-to-peak value between control and any switch. $R_L = 600 \ \Omega$; $f_i = 1 \ MHz$; \overline{E} or Sn square wave between V_{CC} and GND; $t_r = t_f = 6 \ ns$; see Figure 19				
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	-	110	-	mV
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	220	-	mV
f _(-3dB)	-3 dB frequency response	$R_L = 50 \Omega$; see Figure 20				
		$V_{CC} = 2.25 \text{ V}; V_{EE} = -2.25 \text{ V}$	[2] _	160	-	MHz
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	[2] _	170	-	MHz

^[1] Adjust input voltage V_{is} to 0 dBm level (0 dBm = 1 mW into 600 Ω).

^[2] Adjust input voltage V_{is} to 0 dBm level at V_{os} for 1 MHz (0 dBm = 1 mW into 50 Ω).

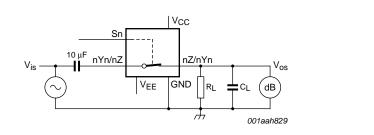
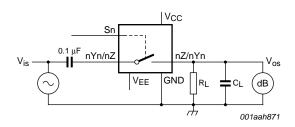
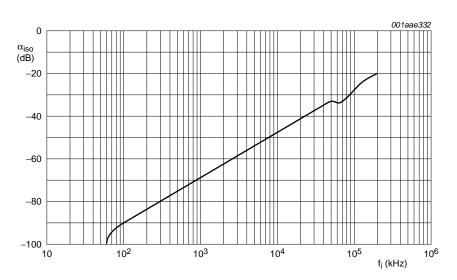


Fig 16. Test circuit for measuring sine-wave distortion



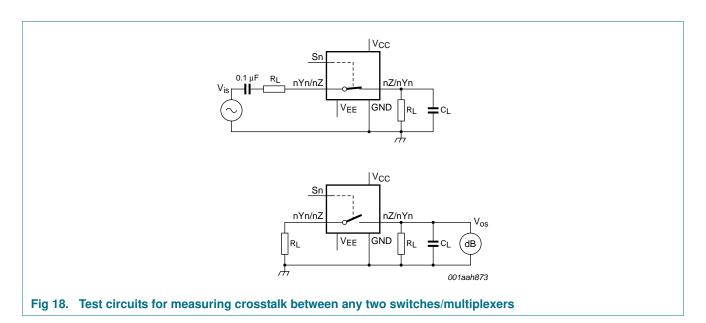
 V_{CC} = 4.5 V; GND = 0 V; V_{EE} = -4.5 V; R_L = 600 $\Omega;$ R_S = 1 k $\Omega.$

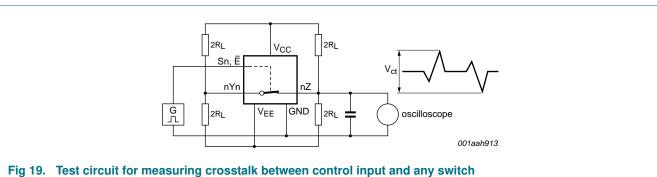
a. Test circuit

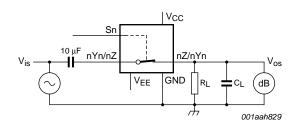


b. Isolation (OFF-state) as a function of frequency

Fig 17. Test circuit for measuring isolation (OFF-state)

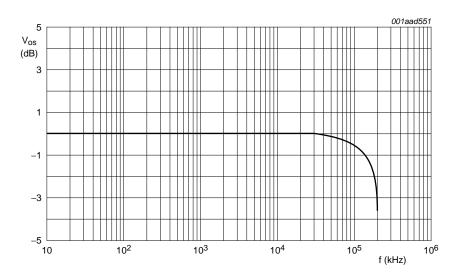






 V_{CC} = 4.5 V; GND = 0 V; V_{EE} = –4.5 V; R_L = 50 $\Omega;$ R_S = 1 $k\Omega.$

a. Test circuit



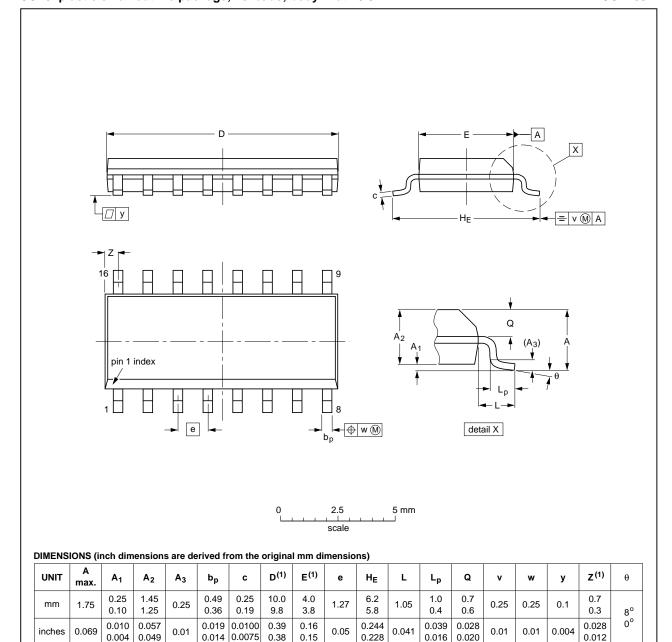
b. Typical frequency response

Fig 20. Test circuit for frequency response

12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

				EUROPEAN ISSUE DATE		
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012			99-12-27 03-02-19	

Fig 21. Package outline SOT109-1 (SO16)

74HC_HCT4053_Q100

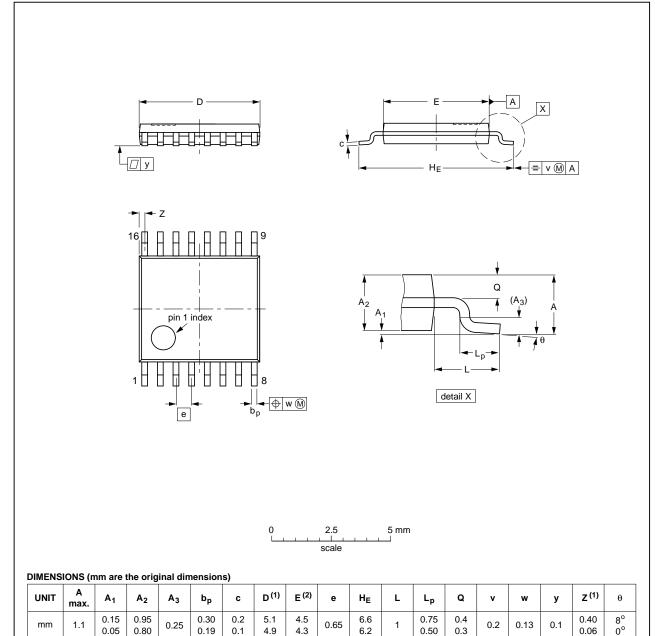
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0.15

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFERENCES			EUROPEAN ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT403-1		MO-153				99-12-27 03-02-18	

Fig 22. Package outline SOT403-1 (TSSOP16)

74HC_HCT4053_Q100

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DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

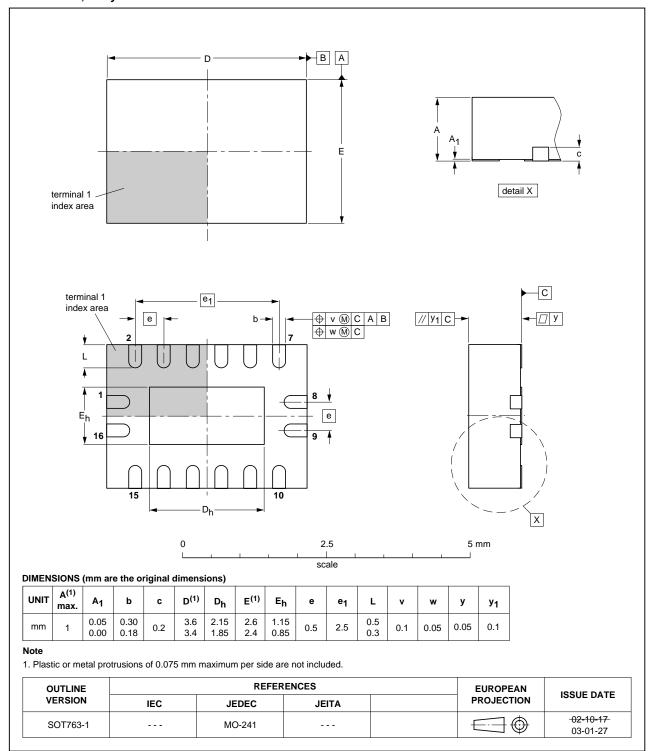


Fig 23. Package outline SOT763-1 (DHVQFN16)

74HC_HCT4053_Q100

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13. Abbreviations

Table 13. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
MIL	Military

14. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT4053_Q100 v.2	20121122	Product data sheet	-	74HC_HCT4053_Q100 v.1
Modifications:	 CDM added 	I to features.		
74HC_HCT4053_Q100 v.1	20120720	Product data sheet	-	-

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Triple 2-channel analog multiplexer/demultiplexer

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NXP Semiconductors

Triple 2-channel analog multiplexer/demultiplexer

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